Full TPC Simulation

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Introduction

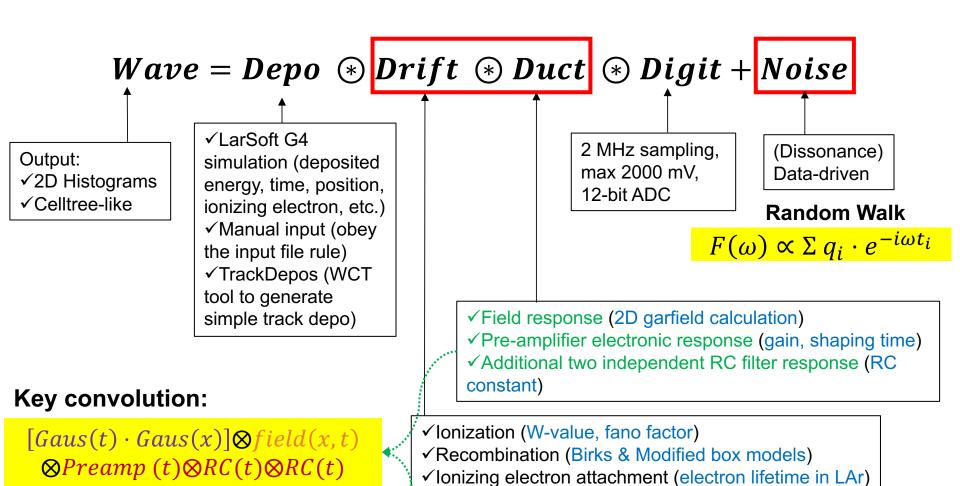
Brett's introduction to wire-cell toolkit (first LEE ana meeting) https://indico.bnl.gov/conferenceDisplay.py?confld=3180

This talk:

- ✓ Functional 5 D's + OutputFrame in wire-cell toolkit (WCT) https://github.com/WireCell/
- √ Fundamental Physics & Math in WCT sim
- ✓ Not include technical/algorithmic details in implementation and speed & memory control

What components we have in the full TPC simulation?

Overview of full TPC simulation



✓ Gaussian diffusion (longitudinal / transverse)

✓ Fluctuation (each step)

Field response (1)

Electron

Weighting

potential

Electric field response

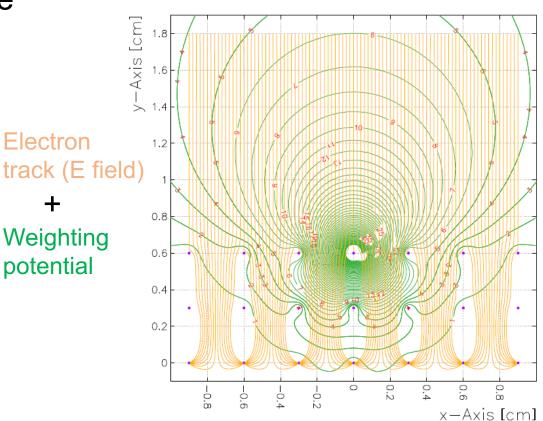
Shockley-Ramo theorem

$$i = q \cdot \vec{E}_w \cdot \vec{v}_q$$

$$\int idt = q \cdot (V_w^{end} - V_w^{start})$$

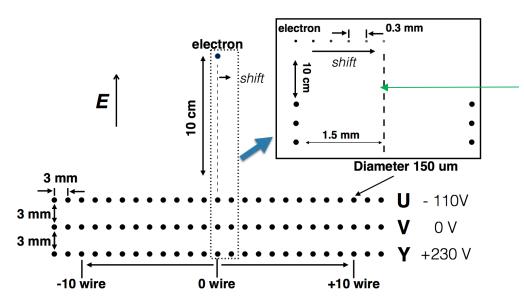
 E_w/V_w : weighting electric field/potential, placing the target wire to the unity potential, and the rest to zero **EM** reciprocity





Field response (2)

- Input 2D Garfield calculation (contribution from adjacent wire regions)
 - Each wire region ±1.5 mm: 6 sub-positions (5 sub-pitches/0.3 mm), the other half is symmetrical (special: 1.5 mm wire pitch boundary for collection planes).
 - Take into account 21 wires $(0 \pm 10) \times 6$ sub-positions = 126 field responses for each plane



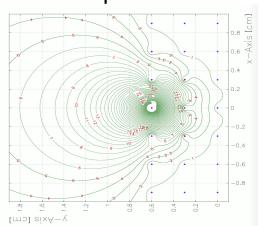
For an electron,

- exact 1.5 mm: bypass collection plane (negligible phase space)
- √ 1.5_{+/-} mm: collected by target/adjacent wires (quite different pathology)

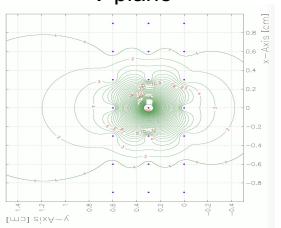
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Field response (3)

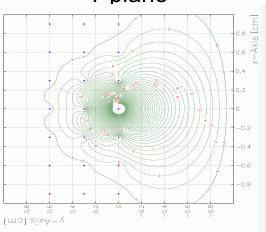
Weighting potential U plane



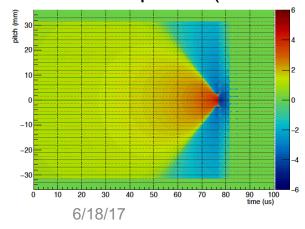
V plane

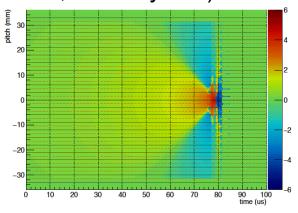


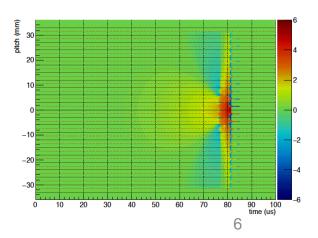
Y plane



Field response (Plot in log scale, arbitrary unit)

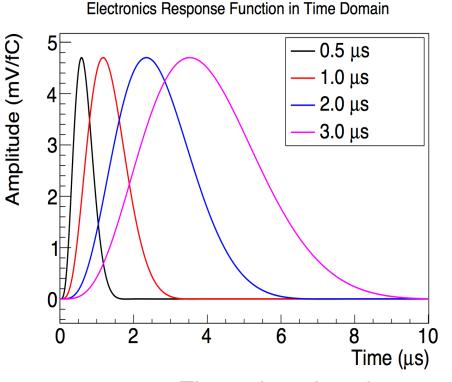


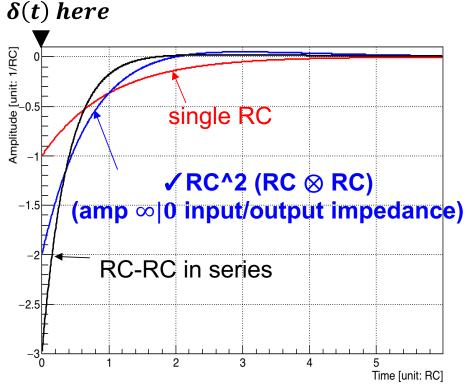




Electronics (impulse) response

 Pre-amp (analytical) RC filter (analytical)





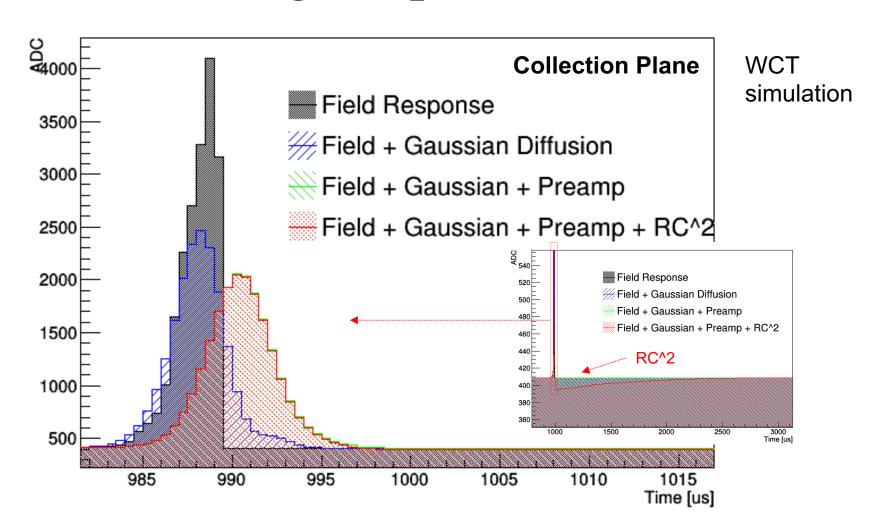
These time-domain responses are obtained by inverse Laplace transform on s-domain responses

Multiple responses

- Multiple electronic responses
 - Mis-configure channels
 - Dead channels
- Multiple field responses [ongoing]
 - Shorted wires

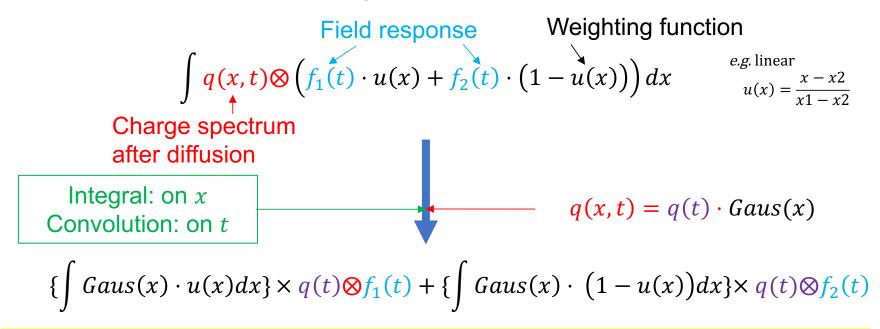
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Point charge depo waveforms



Interpolation of field response

- Real physics has continuous & changing field response
- Interpolation is necessary, 10 sub-pitches are not adequate
- From two nearest field responses



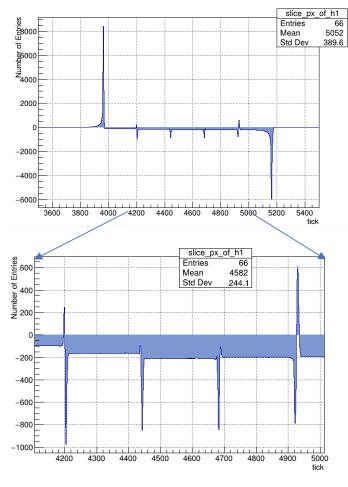
Interpolation of field response \rightarrow re-distribute (weighting) charge depo to the two nearest field response positions against relative distance in x)

Track ~60 cm length in X, 3 mm width in Z

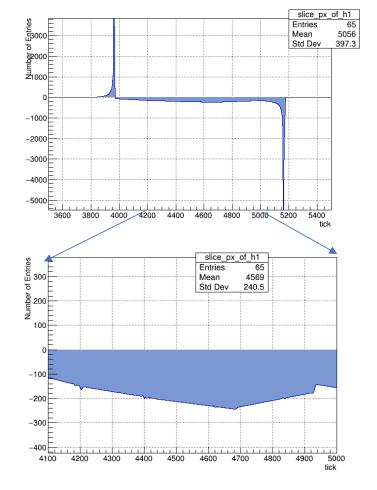
Every 0.003 mm a charge depo along the track without diffusion

Induction Plane (Vplane)

"step" field response from one value to another



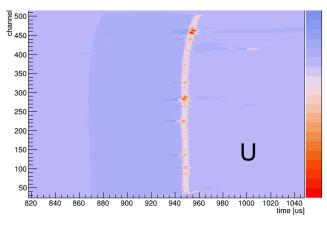
Averaging (weight=0.5)

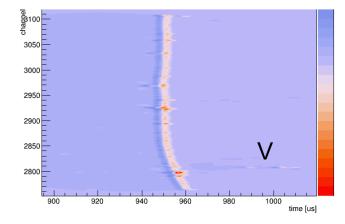


Linear interpolation

A full simulation of LArSoft track

5 GeV muon track from LArSoft G4 simulation

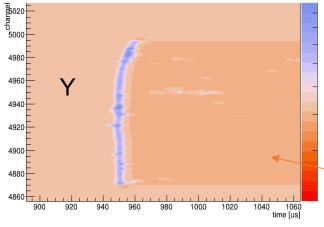




Log scale

Baseline: 1843

Range: 1656 - 1910



Log scale

Baseline: 410

Range: 200 - 974

Tiny negative RC^2 response tail

Front-end ASIC inherent noise

From Milind Diwan

noise type	also called	normalization	Time Domain pulse	s domain	Thermal	
Thermal 1	series white	$\sqrt{2k_{\scriptscriptstyle B}T_{\scriptscriptstyle temp}R_{\scriptscriptstyle S}} imes C_{\scriptscriptstyle m det}$	$\times G \cdot \delta(t - t_j)$	$\times G \cdot e^{-st_j} \blacktriangleleft$	fluctuation in the input transistor	
Thermal 2	parallel white	$\sqrt{2k_{B}T_{temp}/R_{F}}$	$\times G \cdot u(t-t_j)$	$\times \frac{G}{S} \cdot e^{-st_j}$	Transistor bias current and	
Shot noise	parallel white	$\sqrt{qI_{_{leakage}}}$	$\times G \cdot u(t-t_j)$	$\times \frac{G}{S} \cdot e^{-st_j}$	resistors providing the bias voltage	
Flicker noise (1/f or pink)	series 1/f	$C_{ m det} \sqrt{2\pi a_{\scriptscriptstyle F}}$	$\times \frac{G}{\sqrt{\pi \cdot (t - t_j)}}$	$\times \frac{G}{\sqrt{s}} e^{-st_j} \blacktriangleleft$	Charge trapping and de- trapping in the input	
Man made noise	Various couplings	•	e frequency spectrum could be modeled.	. Ignored here,	transistor	

- t_i is uniformly distributed (origin of the fluctuations)
- White noise (e^{-st_j}) can be treated as the origin of other sources of noise (with a scale factor related to frequency)

"Noise Characterization and Filtering in the MicroBooNE TPC", MicroBooNE collaboration, submitted to JINST, arXiv:1705.07341

Inherent noise simulation

See more details at

https://indico.fnal.gov/getFile.py/access?contribId=30&sessionId=12&resId=0&materiaIId=slides&confId=12345

- Key points:
 - White noise can be treat as the origin of all the other source of noise (stochastic behavior)
 - In freq-domain, any noise is a high-dimension random walk in complex plane.
 - The amplitude follows Rayleigh distribution
 - The phase follows uniform in 0-2pi
 - Additivity (sum up all sources of noise)

$$f(x; \sigma) = \frac{x}{\sigma^2} e^{-\frac{x^2}{2\sigma^2}}$$
 (Rayleigh Distribution)
Mean = $\sigma \sqrt{\pi/2}$, Mode = σ , σ = 0.5 · N · L^2

N: number of steps

L: step length

Data-driven noise simulation

- In freq-domain, given a frequency, the mean amplitude is the only parameter we need for noise simulation.
- Two independent Gaussian distributions for real & images parts can simulate the Rayleigh amplitude and uniform phase in the complex plane.
- Data: freq-domain spectra of mean amplitude
 - 1 length for collection plane
 - 13 lengths of wires for U, V planes
 - Series white and pink noise has linear item of $C_{wire} \propto L_{wire}$
 - Linear interpolation based on two nearest lengths

Noise simulation

